

Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

<u>Vishay Semiconductor/Diodes Division</u> <u>VS-ST1230C08K0</u>

For any questions, you can email us directly: sales@integrated-circuit.com



Datasheet of VS-ST1230C08K0 - SCR PHASE CONT 800V 1745A K-PUK Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



www.vishay.com

VS-ST1230C..K Series

Vishay Semiconductors

Phase Control Thyristors (Hockey PUK Version), 1745 A



A-24 (K-PUK)

PRODUCT SUMMARY				
Package	A-24 (K-PUK)			
Diode variation	Single SCR			
I _{T(AV)}	1745 A			
V _{DRM} /V _{RRM}	800 V, 1200 V, 1400 V, 1600 V			
V_{TM}	1.62 V			
I _{GT}	100 mA			
TJ	-40 °C to 125 °C			

FEATURES

- · Center amplifying gate
- · Metal case with ceramic insulator
- International standard case A-24 (K-PUK)
- High profile hockey PUK
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
1		1745	A			
I _{T(AV)}	T _{hs}	55	°C			
1		3200	A			
IT(RMS)	T _{hs}	25	°C			
1	50 Hz	33 500	Δ.			
I _{TSM}	60 Hz	35 100	A			
l ² t	50 Hz	5615	1.42-			
I - 1	60 Hz	5126	– kA ² s			
V _{DRM} /V _{RRM}		800 to 1600	V			
tq	Typical	200	μs			
T _J		-40 to 125	°C			

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$\begin{aligned} I_{DRM}/I_{RRM} & \text{MAXIMUM} \\ \text{AT T}_{J} &= T_{J} & \text{MAXIMUM} \\ & \text{mA} \end{aligned}$				
	08	800	900					
VS-ST1230CK		1200	1300	100				
V3-311230CK	14	1400	1500	100				
	16	1600	1700					

Revision: 16-Dec-13 Document Number: 94395

Datasheet of VS-ST1230C08K0 - SCR PHASE CONT 800V 1745A K-PUK

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



www.vishay.com

VS-ST1230C..K Series

Vishay Semiconductors

PARAMETER	SYMBOL		TEST CON	IDITIONS	VALUES	UNITS
Maximum average on-state current		190° condu	ction. half sine		1745 (700)	А
at heatsink temperature	$I_{T(AV)}$		(single side) co		55 (85)	°C
Maximum RMS on-state current	I _{T(RMS)}	DC at 25 °C	heatsink tempe	erature double side cooled	3200	
		t = 10 ms	No voltage		33 500	
Maximum peak, one-cycle		t = 8.3 ms	reapplied		35 100	A
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}	Sinusoidal half wave, initial T _J = T _J maximum	28 200	
		t = 8.3 ms	reapplied		29 500	
Maximum I ² t for fusing	l ² t	t = 10 ms	No voltage reapplied		5615	kA ² s
		t = 8.3 ms			5126	
		t = 10 ms	100 % V _{RRM}		3971	
		t = 8.3 ms	reapplied		3625	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied			56 150	kA²√s
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π	$x I_{T(AV)} < I < \pi x$	$I_{T(AV)}$), $T_J = T_J$ maximum	0.93	V
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)})$	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			V
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), $T_J = T_J$ maximum			0.17	mΩ
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.16	11152
Maximum on-state voltage	V_{TM}	$I_{pk} = 4000 \text{ A}, T_J = T_J \text{ maximum, } t_p = 10 \text{ ms sine pulse}$			1.62	V
Maximum holding current	I _H	T. 05 °C	anada auprili. 1	2 V registive lead	600	mΛ
Typical latching current	ΙL	T _J = 25 °C, anode supply 12 V resistive load			1000	mA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 Ω , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$	1000	A/µs
Typical delay time	t _d	Gate current 1 A, $dl_g/dt = 1$ A/ μ s $V_d = 0.67 \% V_{DRM}$, $T_J = 25 °C$	1.9	116
Typical turn-off time	t _q	$\begin{split} I_{TM} = 550 \text{ A, } T_J = T_J \text{ maximum, dI/dt} = 40 \text{ A/}\mu\text{s,} \\ V_R = 50 \text{ V, dV/dt} = 20 \text{ V/}\mu\text{s, gate 0 V 100 }\Omega, t_p = 500 \mu\text{s} \end{split}$	200	μs

BLOCKING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNIT S		
Maximum critical rate of rise of off-state voltage	dV/dt	T _J = T _J maximum linear to 80 % rated V _{DRM}	500	V/µs		
Maximum peak reverse and off-state leakage current	I _{RRM} , I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	100	mA		

Datasheet of VS-ST1230C08K0 - SCR PHASE CONT 800V 1745A K-PUK





www.vishay.com

VS-ST1230C..K Series

Vishay Semiconductors

TRIGGERING						
PARAMETER	SYMBOL		VALUES			
PARAMETER	STWIBUL	"5	EST CONDITIONS	typ.	Max.	UNITS
Maximum peak gate power	P_{GM}	$T_J = T_J$ maximum,	$t_p \le 5 \text{ ms}$	1	6	W
Maximum average gate power	P _{G(AV)}	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	(3	VV
Maximum peak positive gate current	I _{GM}			3	.0	Α
Maximum peak positive gate voltage	+ V _{GM}	$T_J = T_J$ maximum,	$T_J = T_J$ maximum, $t_p \le 5$ ms			
Maximum peak negative gate voltage	- V _{GM}	,			5.0	
	I _{GT}	T _J = -40 °C	Maximum required gate trigger/ current/voltage are the lowest	200	-	mA
DC gate current required to trigger		T _J = 25 °C		100	200	
		T _J = 125 °C		50	-	
		T _J = -40 °C	value which will trigger all units 12 V anode to cathode applied	1.4	-	
DC gate voltage required to trigger	V _{GT}	T _J = 25 °C	12 v anode to cathode applied	1.1	3.0	V
		T _J = 125 °C		0.9	-	
DC gate current not to trigger	I _{GD}	T - T maximum	Maximum gate current/ voltage not to trigger is the	10		mA
DC gate voltage not to trigger	V_{GD}	$T_J = T_J \text{ maximum}$	maximum value which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.25		V

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum operating junction temperature range	TJ		-40 to 125	°C		
Maximum storage temperature range	T _{Stg}		-40 to 150			
Maximum thermal resistance,	R _{thJ-hs}	DC operation single side cooled	0.042			
junction to heatsink		DC operation double side cooled	e cooled 0.021			
Maximum thermal resistance,	R _{thC-hs}	DC operation single side cooled	0.006	K/W		
case to heatsink		DC operation double side cooled	0.003			
Mounting force, ± 10 %			24 500 (2500)	N (kg)		
Approximate weight			425	g		
Case style		See dimensions - link at the end of datasheet	A-24 (K-PI	JK)		

△R _{thJC} CONDUCTION								
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION TEST COND		CONDUCTION		TEST CONDITIONS	UNITS
	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE		ı		
180°	0.003	0.003	0.002	0.002				
120°	0.004	0.004	0.004	0.004	$T_J = T_J$ maximum			
90°	0.005	0.005	0.005	0.005		K/W		
60°	0.007	0.007	0.007	0.007				
30°	0.012	0.012	0.012	0.012				

Note

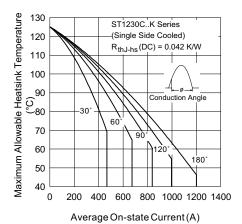
The table above shows the increment of thermal resistance R_{th,JC} when devices operate at different conduction angles than DC

Revision: 16-Dec-13 Document Number: 94395 Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



VS-ST1230C..K Series

Vishay Semiconductors



www.vishay.com

Fig. 1 - Current Ratings Characteristics

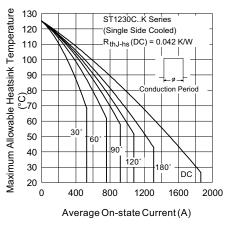


Fig. 2 - Current Ratings Characteristics

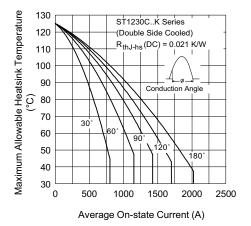


Fig. 3 - Current Ratings Characteristics

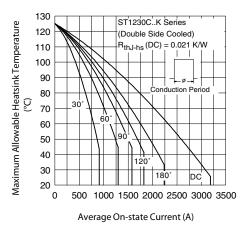


Fig. 4 - Current Ratings Characteristics

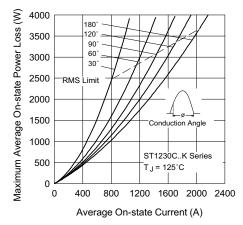


Fig. 5 - On-State Power Loss Characteristics

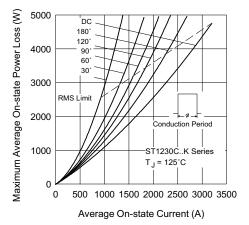


Fig. 6 - On-State Power Loss Characteristics

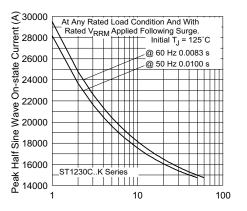
Revision: 16-Dec-13 Document Number: 94395





VS-ST1230C..K Series

Vishay Semiconductors



www.vishay.com

Number Of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

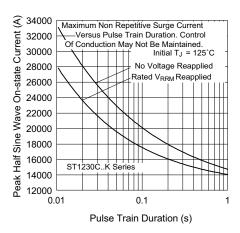


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

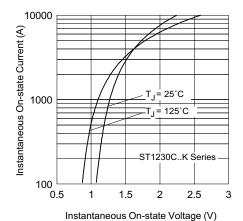


Fig. 9 - On-State Voltage Drop Characteristics

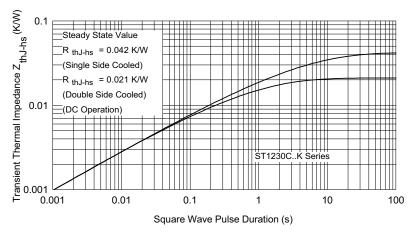


Fig. 10 - Thermal Impedance $Z_{thJ\text{-}hs}$ Characteristics

Datasheet of VS-ST1230C08K0 - SCR PHASE CONT 800V 1745A K-PUK





VS-ST1230C..K Series

Vishay Semiconductors

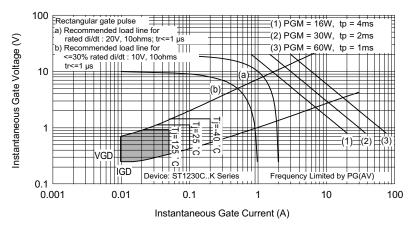
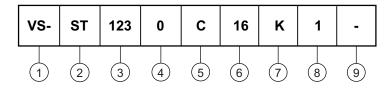


Fig. 11 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

Thyristor

Essential part number

0 = Converter grade

C = Ceramic PUK

6 Voltage code x 100 = V_{RRM} (see Voltage Ratings table)

K = PUK case A-24 (K-PUK)

8 0 = Eyelet terminals (gate and auxiliary cathode unsoldered leads)

1 = Fast-on terminals (gate and auxiliary cathode unsoldered leads)

2 = Eyelet terminals (gate and auxiliary cathode soldered leads)

3 = Fast-on terminals (gate and auxiliary cathode soldered leads)

9 Critical dV/dt: • None = 500 V/µs (standard selection)

• L = 1000 V/µs (special selection)

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95081			

Revision: 16-Dec-13 Document Number: 94395

Datasheet of VS-ST1230C08K0 - SCR PHASE CONT 800V 1745A K-PUK Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



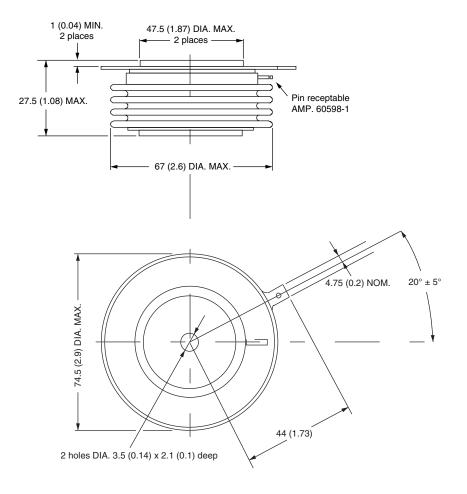
Outline Dimensions

Vishay Semiconductors

A-24 (K-PUK)

DIMENSIONS in millimeters (inches)

Creepage distance: 28.88 (1.137) minimum Strike distance: 17.99 (0.708) minimum



Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)

Document Number: 95081 Revision: 02-Aug-07



Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of VS-ST1230C08K0 - SCR PHASE CONT 800V 1745A K-PUK

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



VISHAY.

www.vishay.com

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Revision: 13-Jun-16 1 Document Number: 91000